Supplementary Information

A novel graphene barrier against moisture by multiple stacking large-grain graphene

Ploybussara Gomasang ¹, Kenji Kawahara ², Kenta Yasuraoka ³, Mina Maruyama ³, Hiroki Ago ², Susumu Okada³, and Kazuyoshi Ueno ^{1, 4,*}

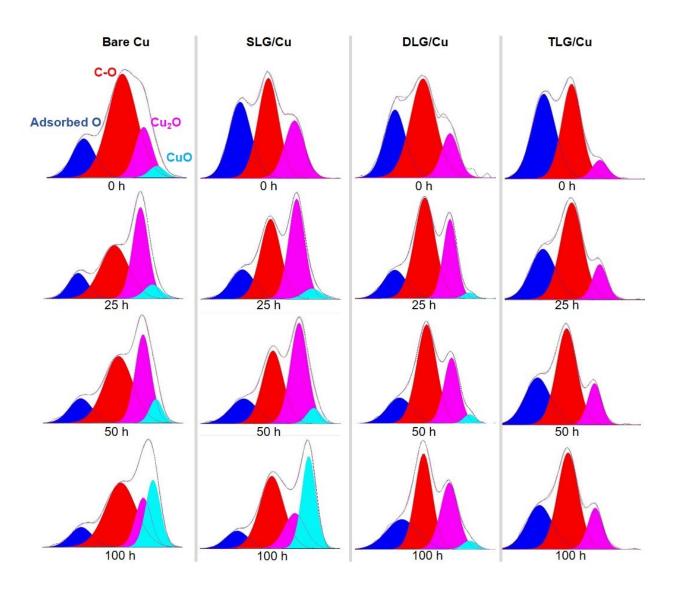
¹ Graduate School of Engineering and Science, Shibaura Institute of Technology, Koto, Tokyo 135-8548, Japan

² Global Innovation Center, Kyushu University, Kasuga, Fukuoka 816-8580, Japan

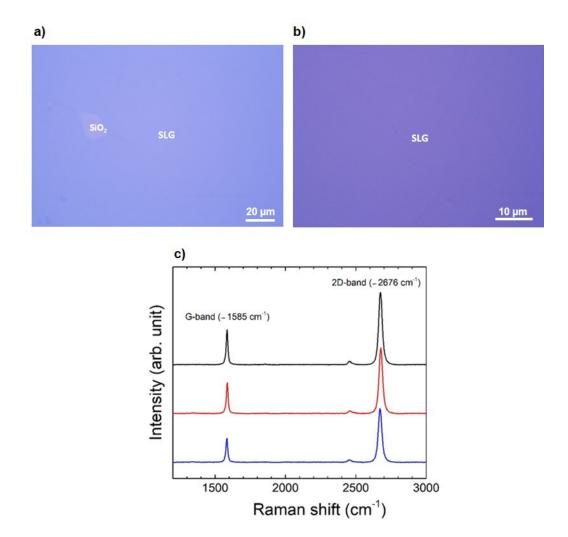
³ Graduate School of Pure and Applied Sciences, University of Tsukuba, Tsukuba, Ibaraki, 305-8577, Japan

⁴ SIT Research Center for Green Innovation, Koto, Tokyo 135-8548, Japan

^{*}ueno@shibaura-it.ac.jp



Supplementary Figure S1. O 1s curve fittings showing the amount of O atom in Cu₂O, CuO, C–O bonds, and adsorbed O on each sample surface. The evolution of O atoms in the Cu₂O and CuO components of the O 1s spectra corresponds to the analysis of the Cu 2p spectra. Adsorbed O and C–O components were omitted in the calculation of O/Cu ratios.



Supplementary Figure S2. Characterization of SLG. Panels (a and b) show Optical micrographs of SLG grown on Cu(111)/sapphire substrate after transferring the film to a SiO_2 (300 nm)/Si substrate. For panel (a), we chose the area with a hole showing bare SiO_2 to demonstrate that the growth of uniform SLG, almost free from multilayers. Panel (c) shows Raman spectra measured on the transferred SLG surface (excitation wavelength of 532 nm).